

PST 64DN04

**HIGH POWER DIODE FOR MEDIUM FREQUENCY WELDING
WITHOUT HOUSING ULTRATHIN DEVICE**

Features

- High current capability
- Very low thermal impedance
- High power cycling capability

ELECTRICAL CHARACTERISTICS AND RATINGS

Reverse blocking

Device Type	V _{RRM} (1)	V _{RSM} (1)
PST 64DN04	400 V	500 V

V_{RRM} = Repetitive peak reverse voltage

V_{RSM} = Non repetitive peak reverse voltage (2)

Notes:

All ratings are specified for T_j=25 °C unless otherwise stated.

(1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range -40 to +180 °C.

(2) 10 ms max. pulse width

(3) Maximum value for T_j = 180 °C.

Repetitive peak reverse leakage current	I _{RRM}	100 mA (3)
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Conducting

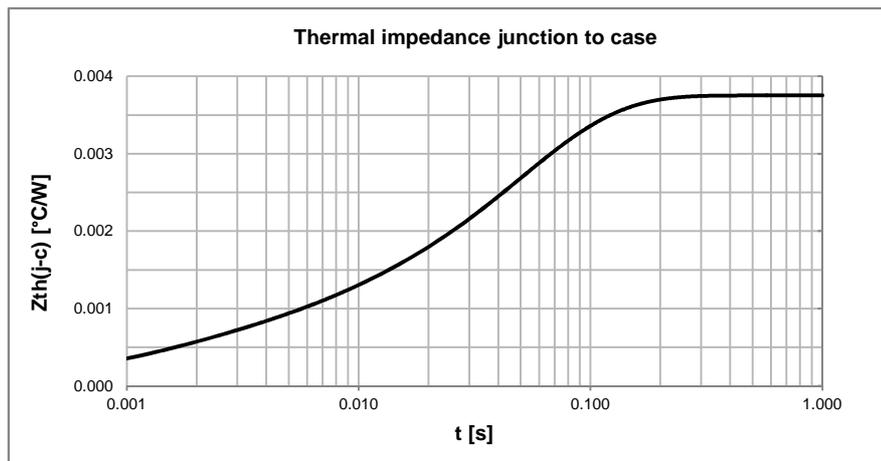
Parameter	Symbol	Min	Max	Typ	Unit	Conditions
Average value of forward current	I _{F(AV)}		8500		A	50 Hz sinewave, 180° conduction, T _c = 129 °C
RMS value of forward current	I _{F(RMS)}		13345		A	
Peak one cycle surge (non repetitive) current	I _{FSM}		95		kA	50 Hz sinewave, 180° conduction, T _j = T _{jmax} , V _R = 0
I square t	I ² t		45125		kA ² s	T _j = T _{jmax}
Peak forward voltage	V _{FM}		0.98		V	Forward current 10 kA, T _{jmax}
Threshold voltage	V _{F(TO)}		0.7		V	T _j = T _{jmax}
Forward slope resistance	r _F		0.029		mΩ	T _j = T _{jmax}

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Thermal and mechanical characteristics and ratings

Parameter	Symbol	Min	Max	Typ	Unit	Conditions
Operating temperature	T_j	-40	180		°C	
Storage temperature	T_{stg}	-40	180		°C	
Thermal resistance junction to case	$R_{th(j-c)}$		0.0038		°C/W	Double side cooled , DC
Thermal resistance junction to case	$R_{th(j-c)}$		0.0046		°C/W	Double side cooled, 180° sin
Thermal resistance case to sink	$R_{th(c-s)}$		0.0020		°C/W	Double side cooled, mounting surfaces smooth, flat and greased
Mounting force	F	60	80		kN	
Weight	W		150		g	



Analytical expression for $Z_{th(j-c)}$

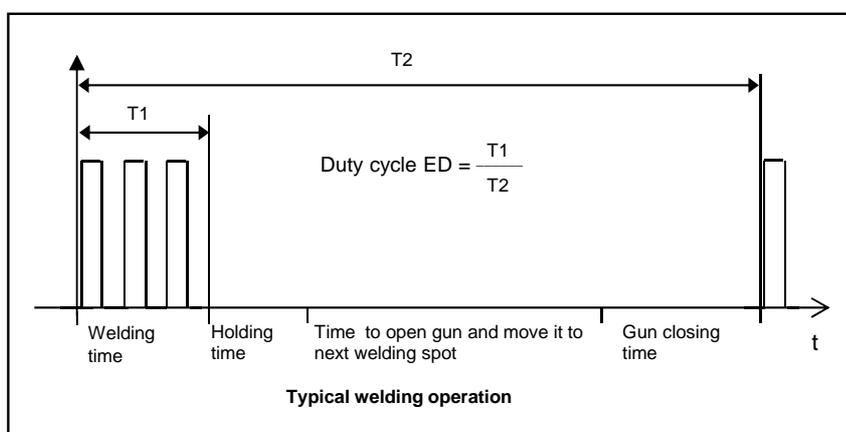
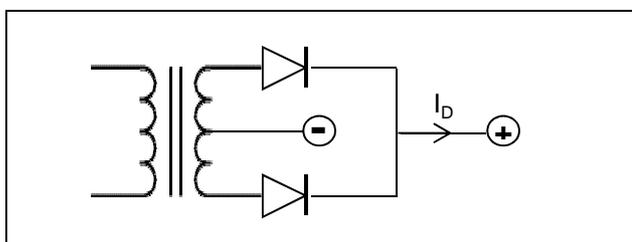
$$Z_{th(j-c)}(t) = \sum_i A_i \cdot (1 - \exp(-t / \tau_i))$$

i	1	2	3	
A_i	4.6E-04	2.9E-03	3.9E-04	[°C/W]
τ_i	5.4E-03	5.0E-02	1.2E-03	[s]

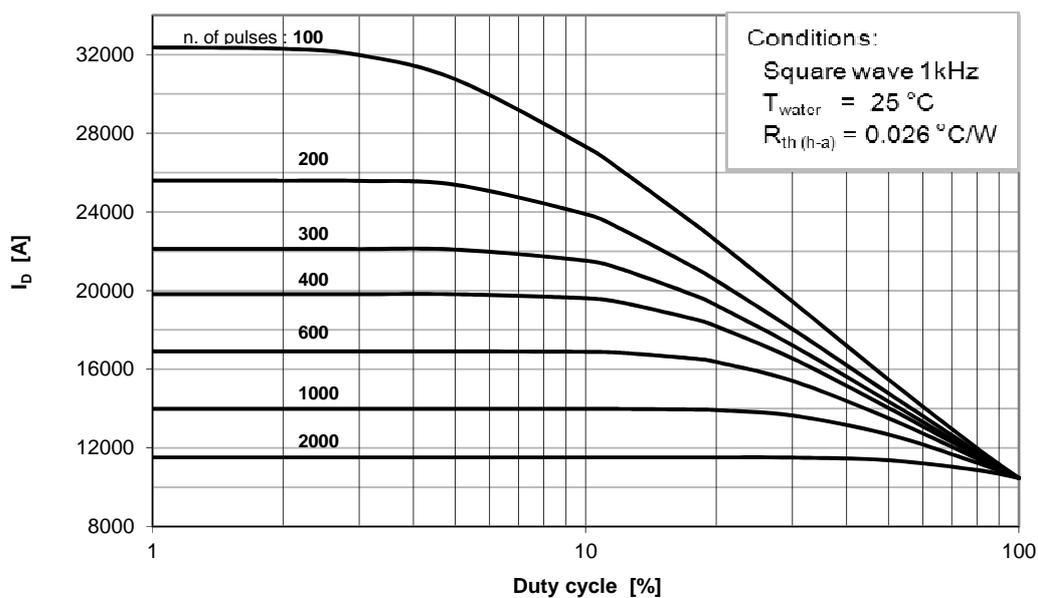
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Output current (I_D) capability for center tap configuration

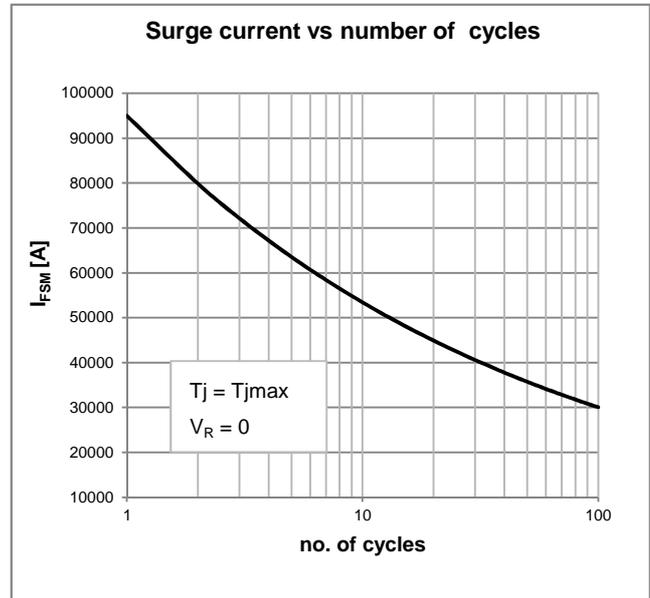
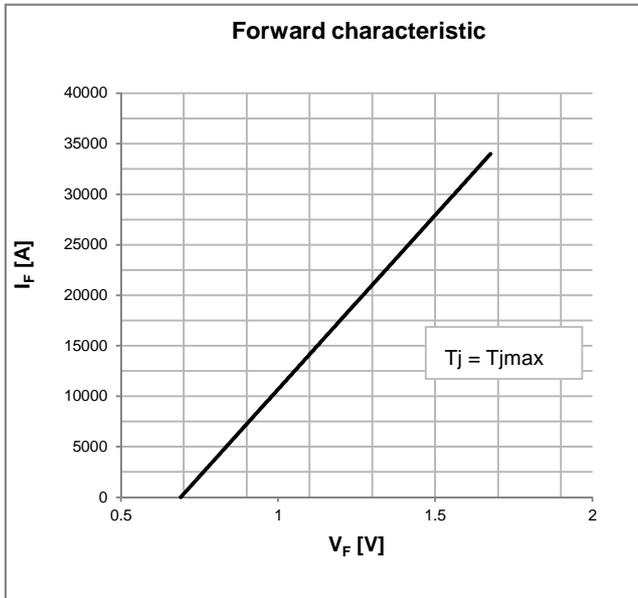


Output current capability

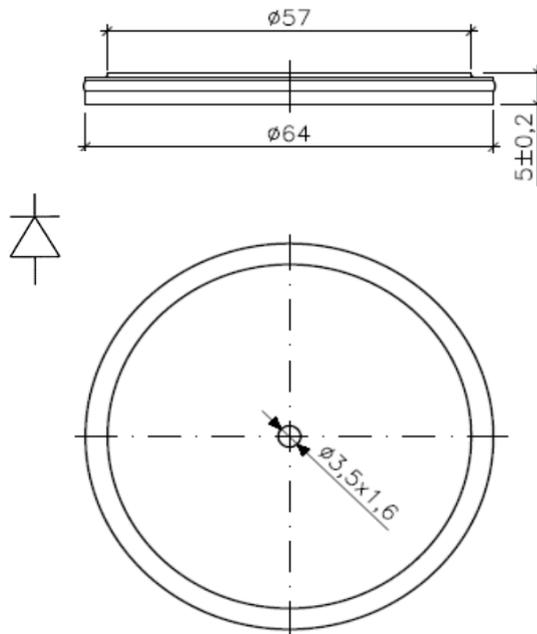


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OUTLINE AND DIMENSIONS



Notice

- We recommend to protect the diode with a temperature resistant O-Ring.
- All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink surfaces with flatness < 0.03 mm and roughness < 2 μ m